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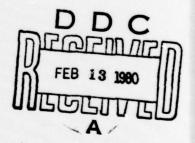
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Solid State Structure and Electronic Properties of
A Mixed-Valence Two-Dimensional Metal, KCu/S

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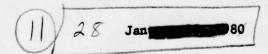
David B. Brown Jon A. Zubieta P. A. Vella James T. Wrobleski Timothy Watt, William E. Hatfield, and Peter Day.

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Solid State Structure and Electronic Properties of

A Mixed-Valence Two-Dimensional Metal, KCu_4S_3

David B. Brown^{1a}, Jon A. Zubieta^{1b}, P. A. Vella^{1b}, James T. Wrobleski^{1a}, Timothy Watt^{1a}, William E. Hatfield^{1c}, and Peter Day^{1d}.

Contribution from

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Abstract

 KCu_4S_3 , prepared by the high temperature reaction of copper, potassium carbonate, and sulfur, crystallizes with a unique layered structure. Double layers of tetrahedrally - coordinated (by S) copper ions are separated by layers of potassium ions. Although formally a mixed-valence Cu(I,I,I,II) complex, all copper ions are crystallographically equivalent. Consistent with its Robin and Day Class III designation, KCu_4S_3 exhibits electrical conductivity characteristic of a metal. Room temperature compaction conductivities of \underline{ca} . $4000~\Omega^{-1}$ cm⁻¹ increase to \underline{ca} $60000~\Omega^{-1}$ cm⁻¹ at 20K. The metallic nature of this two-dimensional material is supported by the temperature independent paramagnetism and the metallic reflectivity through the visible and near ultraviolet region of the spectrum.

Introduction

In recent years there has been an intensive search for new materials which exhibit high electrical conductivity. Several factors motivate research in this area, including the desire to find new materials with high superconducting transition temperatures. This has been approached by both systematic modifications of known types of superconducting materials, and also by the search for new types of superconducting materials, particularly the elusive "excitonic" superconductor (2). At a more fundamental level, activity in the field has been sustained by the discovery of several new classes of conducting materials, most specifically the one- and two-dimensional conductors which have proven so important in our understanding of the electrical properties of solids.

One class of compounds which have been widely studied are the transition metal chalcogenides, typified by TaS2, which crystallize with layer structures (3). Although most common with the early transition metals, a large number of compounds are known which have certain structural similarities, namely strong covalent metal-sulfur bonding within a two-dimensional sheet and either weak (van der Waals) or ionic interactions between layers. Many of these materials exhibit either metallic (TaS2) or semiconducting (MoS2) electrical behavior, and in each case the properties are highly anisotropic. For example, one crystalline modification of TaS2 exhibits metallic conductivity in the layers but semi-metal or semiconducting behavior perpendicular to the layers, with an anisotropy in the resistivity as high as 500 at low temperatures (4). Many of these materials exhibit superconductivity at low temperature. Several of these compounds are susceptible to chemical modification. TaS2, for example, reacts with either organic bases such as pyridine (py) or with alkali metals by intercalation. The lattice expands perpendicular to the planes in order to accomodate

the intercalate between the layers. Although the magnitude of the parallel conductivity does not vary greatly in such materials, both the anisotropy in the conductivity and the superconducting transition temperatures do change. Thus, the metal sulfides and their ternary intercalates provide a rich area for examining high two-dimensional conductivity.

Although layered structures are relatively common among the sulfides of the early transition metals, the later members of the transition series, such as copper, tend to form sulfides where three-dimensional interactions prevail. We were intrigued by the report (5) that KCu_4S_3 adopts a layered structure. Moreover, the reported structure appears to be unique in that it contains double layers (S-Cu-S-Cu-S) separated by potassium ions. Since the conductivity was reported to be high (40 Ω^{-1} cm⁻¹) there appeared to be physical, as well as structural, similarities to the sulfides of the early transition metals. Based on the empirical formulation, KCu_4S_3 is a formally mixed-valence Cu(I,I,I,II) complex. The crystallographic results suggest that all coppers are equivalent, thereby placing the material in the Robin and Day (6) class III-B. Although there are relatively few materials which may be so designated, they are predicted by theory, and generally found by experiment, to exhibit metallic conductivity. The importance of mixed-valence in the design of highly conducting materials has been emphasized recently. (7)

Prompted by the reported properties of KCu_4S_3 , we have examined this compound in more detail. The reported structure is based on powder data, and we have carried out a complete single-crystal X-ray structure determination. We also report here the magnetic and electrical properties of KCu_4S_3 , including temperature-dependent four-probe conductivity studies, magnetic susceptibility measurements, electronic spectral measurements, and single-crystal conductivity measurements.

Experimental

 $\mathrm{KCu_4S_3}$ was prepared as described in the literature (5). Attempts to systematically vary this procedure in order to obtain large single crystals were generally unsuccessful, and there was no apparent correlation between reaction parameters and the quality of the resulting product.

Electrical conductivities for pressed pellets were measured using two different probe geometries. Pellets were generally pressed at ca. 100,000 psi, although measured conductivities were not sensitive to the pressure used in pellet preparation. Room temperature conductivities were measured using a standard inline four-probe technique with pressure contacts (8). Commercial probes (Alessi Industries) with both 0.67 and 1.0 mm probe spacings were employed. Measured conductivities were corrected for finite pellet thickness. Measurements were also made using the van der Pauw technique (9). A locally designed Teflon sample holder with spring-loaded stainless steel pressure contacts was used for these measurements. Low temperatures were obtained by suspending this assembly in the Faraday balance shroud of an Air Products Co. Displex CS-202 closed cycle helium refrigerator. Currents were imposed with a Keithley Model 225 current source and voltages measured with a Keithley nanovoltmeter. Single crystal conductivities parallel to the two-dimensional sheets of the crystals employed standard probe configurations. Current probes were attached to opposite ends of the crystals using silver print, and voltage probes were placed on the surface of the crystal using joy-stick micromanipulators (The Micromanipulator Co., Escondido, CA.). Both pressure and silver print contacts were used for the voltage probes.

Magnetic susceptibility data were collected using a Princeton Applied Research Model 155 vibrating sample magnetometer (VSM) which was operated at 10kOe. The VSM magnet (Magnion H-96), power supply (Magnion HSR-1365) and associated field control unit (Magnion FFC-4 with a Rawson-Lush model 920 MCM rotating-coil gauss meter) were calibrated against NMR resonances at 10kOe and the field set accuracy was found to be better than 0.15%. The magnetometer was initially calibrated against HgCo(NSC)₄ (10), and the calibrations were checked against a sample of (NH₄)₂Mn(SO₄)₂·6H₂O (11). The results using these two standards agreed to within 2% which represents the upper limit to the uncertainty in the measurements. Powdered samples of the calibrants and compounds used in this study were contained in precision milled Lucite sample holders. Approximately 150 mg. of each were used. Diamagnetic corrections for the constituent atoms were made using Pascal's constants, and a correction for temperature independent paramagnetism was estimated from tabulated data (12-14).

Specular reflectivity measurements were made at room temperature with a Unicam SP700 Spectrophotometer equipped with an SP735 reflectance attachment. About a dozen of the small plate-like crystals were cemented to a matt-black background to make a reflecting surface 3-4 mm². Reflectivity was determined with respect to a polished aluminum disk.

Collection and Reduction of Diffraction Data: KCu_4S_3 crystallizes as square platelets, several of which were mounted along an edge. Preliminary cell dimensions were obtained from Weisenberg and precession photographs of the crystals taken with $CuK\alpha$ (λ = 1.5418A) radiation. Using these approximate cell dimensions from the film measurements, 18 reflections with $30^{\circ} < 20 < 40^{\circ}$ were accurately centered in the counter window of a Seimens AED quarter-circle automated diffractometer.

A least squares procedure was used to obtain a best fit between the observed and calculated values of χ , ϕ , and 20 for these reflections. The cell parameters and relevant crystal data are presented in Table I. As the photographs showed no systematic absences, the space groups P4, P4, P4/m, P422, P4mm, P42m, P4m2, and P4mm must be considered. The space groups P4 and P4mm proved to be inconsistent with the unit cell contents, while P4 is inconsistent with the observed intensities for (hk0) reflection with 1+k = odd which appear very weak. Of the remaining space groups, P4/mmm was chosen initially as the highest symmetry group which contains the other space groups of the 4/mmm Laue symmetry as sub-groups. Subsequent successful refinement of the structure in this space group and the failure of refinements in lower symmetry groups to improve the discrepancy factor confirmed the choice of space groups. The equivalence of F(hk1) and F(kh1) and the statistical test for centricity confirmed the choice of Laue symmetry 4/mmm rather than 4/m.

Intensity data were collected on a Seimens AED automated diffractometer using MoKa radiation filtered through zirconium foil. A scan speed of 1°/min was employed in measuring each reflection by the moving-counter/moving crystal $(\omega/2\theta)$ scan method with a scan range of 1.6° in 20. A five value measurement was performed on each reflection in the following fashion: the angles were set to the center of the reflection which was then scanned through 0.8° toward negative θ and the count I_1 recorded, the background was measured for 1.6 min and recorded as I_2 ; the reflection was scanned through 1.6° toward positive θ and the count I_3 was recorded; the background I_4 on the second side of the peak was counted for 1.6 minute; and finally, the peak was scanned back through 0.8° and the count I_5 was recorded. Since the counting times $t_2 + t_4 = t_1 + t_3 + t_5$, the net count is given by the relationship I net = 1/2 $[(I_1 + I_3 + I_5) - (I_2 + I_4)]$.

The intensities of three standard reflections used to monitor diffractometer and crystal stability fluctuated by + 1.0% over the period of the data collection.

The observed intensities were corrected for background, Lorentz, polarization and absorption effects. Only reflections with I>2.58 σ (I) were included in the refinement. The observed data were not corrected for secondary extinction. Solution and Refinement of the Structure (15): A sharpened Patterson map was computed using the corrected data. The map was contoured and solved for the positions of the copper atom and one sulfur atom (R=32%). The positional coordinates were used to produce a set of phased structure factors for a difference Fourier synthesis which revealed the positions of the potassium and sulfur atoms. The positional and anisotropic thermal parameters of the atoms were refined by a least squares method for six cycles, leading to convergence at .062 and .074 for the discrepancy factors $R_1 = \Sigma ||Fo| - |Fc||/\Sigma |Fo|$ and $R_2 = (\Sigma \underline{w}(|Fo| - |Fc|)^2/\Sigma \underline{w}|Fo|^2)^{1/2}$, respectively where the weights, \underline{w} were taken as $1/\sigma^2$. Scattering factors for the zerovalent Cu,K, and S atoms were taken from International Tables (16).

Results: The final positional and thermal parameters for KCu_4S_3 are given in Table II. The pertinent bond lengths and angles are given in Table III. Figure 1 provides the atom labelling scheme and shows the 50% probability ellipsoids for an isolated CuS_4 tetrahedron.

As indicated by the unit cell composition, the atoms must sit at special positions in the cell. The four copper atoms in the cell are located in positions of four-mold multiplicity (Wyckoff position \underline{i} in P4/mmm). The single K atom must sit at a position possessing the full symmetry of the space group, Wyckoff position b in the reference space group, as must S1 which was located at Wyckoff position a. The S2 atoms are at Wyckoff positions g.

Although the empirical formula suggests a species which formally contains both Cu^{1+} and Cu^{2+} , all copper coordination sites are equivalent, with the copper enjoying distorted tetrahedral coordination to the sulfur atoms. The overall structure may be described in terms of double layers built of CuS4 tetrahedra, the layers being interleaved with K⁺ ions surrounded by eight S2 atoms at the vertices of a cube. Figure 2 illustrates the double layers of CuS4 tetrahedra, generated by the sharing of five edges and four vertices by each CuS4 tetrahedron. This diagrammatic representation reveals an unusual feature of the structure, the absence of Cu density at the octahedral sites generated by the sulfur atom packing. A schematic representation of a single layer viewed parallel to the c-cell axis (Figure 3) shows the edge-sharing of CuS₄ tetrahedra with four tetrahedra adjacent in the same layer and the sharing of vertices with two additional polyhedra. A fifth edge is shared with a tetrahedron in the second layer. Sulfur atoms S2 are shared by four tetrahedra, while each sulfur of the central layer, S1, participates in eight polyhedra, with the adjacent Cu atoms at the corners of a cube, at a distance of 2.4506(9)A.

It should be emphasized that these structural results are in virtually exact agreement with those obtained nearly thirty years ago from powder diffraction data (5). Conductivity

Room temperature electrical conductivities were measured for six different preparations of KCu_4S_3 using pressed pellets and four-probe techniques. Measurements were made using both in-line probes and the van der Pauw technique. In each case, pressure contacts were used. Values of the conductivity obtained using the in-line probes have been corrected for pellet thickness (8). Measurements were considered acceptable only after determining that each sample exhibited ohmic behavior. The average value of Γ room temperature conductivity, determined from eleven separate experiments, was found to be σ = 4.1 ± 1.1 x 10⁺³ Ω ⁻¹ cm⁻¹.

The temperature dependence of the conductivity is that of a metal, the resistivity decreasing with decreasing temperature. Figure 4 shows the variation in σ with temperature in the interval 20-300°K. Although not shown in Figure 4, measurements at lower temperatures exhibit a continuing smooth variation. At 20K the conductivity has risen by a factor of approximately 15 from its room temperature value, to $\sigma \simeq 6 \times 10^4 \ \Omega^{-1} \ cm^{-1}$.

Measurements of the in-plane single crystal conductivity had a high scatter. This may probably be attributed to the difficulty in obtaining single crystals large enough for accurate placement of electrodes and the difficulty in measuring crystal dimensions. Crystals were always formed as extremely thin fragile plates (ca 0.03 mm) and were rarely as large as 1 mm² on the surface. Average values of the conductivity (13 crystals) within the two-dimensional sheets were found to be $\sigma \simeq 3 \times 10^{+3} \ \Omega^{-1} \ cm^{-1}$ at room temperature.

Magnetism. The magnetic susceptibility data for KCu_4S_3 in the temperature range 4.2 to 65 K are shown in Figure 5, where it may be seen that the magnetic susceptibility is largely constant from high temperatures to below 30 K, at which point it begins to increase rather rapidly. When plotted as χ^{-1} versus temperature the data below 15 K follow a Curie-Weiss law, $\chi = C/(T-\theta)$, with C=0.00477 and $\theta=0.16$. This behavior is characteristic of the susceptibility of a metallic system with the presence of a low concentration of paramagnetic sites. At high temperature the measured susceptibility is the sum of the Pauli temperature independent paramagnetism and the Curie-Weiss paramagnetism, while at low temperatures the Curie paramagnetism is dominant. If g is taken to be 2.1, a reasonable value for copper(II), the most likely contaminant, then the percent impurity can be estimated from the Curie constant

to be 1.4. The Curie-Weiss portion of the paramagnetism calculated from the expression given above was subtracted from the measured magnetic susceptibility to give a constant value of 72×10^{-6} emu/mole in the temperature range 40-65K. Discussion

Although a large number of copper-sulfide phases are known (Table IV), KCu_4S_3 and its analogs are unique. Most copper sulfides form stoichiometric phases containing, formally, a single oxidation state of copper. The major exception to this generalization is the system $Cu_{2-x}S$, $0 \le X \le 0.2$, where a range of non-stoichiometric, and formally mixed-valence, phases are known. By contrast, KCu_4S_3 forms as a discrete mixed-valence system, with no apparent variability in composition, under a variety of experimental conditions. (A different mixed-valence phase, $K_3Cu_8S_6$, forms at higher temperatures.) Under conditions comparable to those used in the preparation of KCu_4S_3 , silver forms the singly-valent species $K_2Ag_4S_3$ (42).

Although KCu_4S_3 is formally a mixed-valence (non-integral oxidation state) compound, it is clear from the structural results that all copper ions are equivalent. The material is thus a Robin and Day Class III-B mixed-valence system, and as such should have certain predictable physical properties. As discussed below, its conductivity, magnetism, and spectral properties are consistent with this classification.

The three-dimensional structure of KCu_4S_3 is significantly different from those previously reported for copper-sulfide phases of varying compositions. A common feature of the copper-sulfide and more complex phases presented in Table IV is the formation of three-dimensional networks; the occurrence of the double-layer

structure appears to be unique to KCu_4S_3 and $RbCu_4S_3$ (5).

The two independent Cu-S distances are similar to those observed previously for tetrahedral Cu-S lattices, which range from 2.13 to 2.59 Å (See Table IV). In addition to the four sulfur neighbors, each copper enjoys close contacts with four coppers at 2.757Å in the same layer and with one copper at 2.970(2)Å in the adjacent layer; these copper-copper interactions are similar to those observed in $NH_4Cu_7S_4$ (24) where there are four neighbor Cu atoms at 2.83Å and at 2.94Å.

As a Class III-B mixed-valence solid, KCu_4S_3 is expected to exhibit metallic conductivity. Indeed, our initial interest in this material was aroused by the report that a compaction of the material exhibited a room temperature conductivity of $40~\Omega^{-1}~{\rm cm}^{-1}$. Our work shows that the conductivity is two orders of magnitude higher. It is probable that the original measurements used a two-probe technique, and for such a highly conducting material contact resistances would dominate. As expected, the temperature dependence is that of a metal, the conductivity increasing with decreasing temperature. The conductivity exhibits a linear 1/T dependence in the temperature range examined.

Although measured with only low precision, the single crystal conductivity, σ_{11} , is comparable to the bulk conductivity. Assuming highly anisotropic electrical properties, as suggested by the structure, σ_{11} should be larger than the compaction conductivity (43). The relatively low value for σ_{11} may reflect experimental difficulties in measurements on these single crystals or it may suggest that the electrical properties are not so highly anisotropic as expected from the structure. Alternatively, the compaction value may be artifically high as a consequence of preferential alignment of these plate-like crystals. The fact that bulk conductivities show no significant differences for thoroughly

ground samples and direct crystal compactions suggests that preferential alignment is not a dominant factor.

The value of the conductivity is similar to that of other known metallic materials with layer structures. Thus, σ_{11} for various crystalline modifications of MX₂, M = Nb, Ta; X = S, Se, is typically 5000-10000 Ω^{-1} cm⁻¹ (44).

Goodenough (45) has defined a critical internuclear separation, $D_0(n,1)$, which is dependent on the electronic configuration of the metal and the identity of bridging ligands. When metal ion separations are below this critical distance, high mobility collective electrons should be present, and metallic behavior should result. For a d⁹ Cu⁺² complex with sulfide ligands, this distance is predicted to be approximately 3.10 A°. KCu₄S₃, with four Cu-Cu separations of 2.76 A° and one of 2.97 A°, clearly satisfies the Goodenough criterion, and consequently, its metallic properties are consistent with the theory. Because ${
m Cu}^{+1}$, with a ${
m d}^{10}$ electronic configuration, should give rise only to filled bands, metallic conductivity is not expected for materials containing only that oxidation state. Although several ${\rm Cu}^{+1}$ systems are known (NH $_4{\rm Cu}_7{\rm S}_4$, KCuS, KCu $_3{\rm S}_2$, BaCu $_4{\rm S}_3$) which satisfy the Goodenough criterion, electrical properties are apparently known only for BaCu₄S₃ (46). This material has a high conductivity ($\underline{ca} \, 5 \, \Omega^{-1} \, \text{cm}^{-1}$) which is largely temperature independent. There are apparently no known simple Cu⁺² sulfides. Covellite, CuS, has a nominal Cu⁺² formulation, but is found to contain the ion S_2^{2-} (e.g., CuS = $Cu_2S \cdot CuS_2$). Although the oxidation states of copper are distinguishable in that case (Robin and Day Class II), the material is metallic. KCu_4S_7 might be predicted to be metallic either as a result of its mixed-valence nature or as a consequence of the Goodenough relations. Apparently neither criterion is sufficient, since Cu_{1.96}S is obviously mixed-valent, and has Cu-Cu separations of 2.64 and 2.97 A°, yet exhibits semiconducting behavior. It is clear that the relationship between structure and electrical properties in copper

sulfides requires further examination.

Magnetism

The Pauli spin magnetization of the conduction electrons in a free electron gas metal is given (47) by

$$M = \frac{3N\mu^2 B}{2k_B T_F}$$

Because the magnetic field induces a diamagnetic component, the total magnetization of a free electron gas is

$$M = \frac{Nu^2 B}{\frac{K_B T_F}{E_F}} = \frac{N u^2 B}{\frac{E_F}{E_F}}$$

where $\underline{\mu}$ is the Bohr magneton (.921 x 10^{-20} erg/0e), $\underline{\beta}$ is the magnetic field intensity, \underline{k}_B is the Boltzmann constant, \underline{T}_F is the Fermi temperature, and \underline{E}_F is the Fermi energy. \underline{E}_F may be estimated from

$$E_{\rm F} = \frac{\pi^2}{2m} \left(\frac{3\pi^2 N}{V} \right)^{2/3}$$

where m is the mass of the electron and N/V is the conduction electron concentration. For KCu_4S_3 , with a single hole in the d-orbital manifold, we expect one carrier per formula unit. Knowing the molecular volume (84.85 cm³), N/V is then 7.1 x 10^{21} cm⁻³, and the Fermi energy is calculated as $E_F = 2.19 \times 10^{-12}$ erg. The predicted magnetic susceptibility is then $\chi_p = 23.3 \times 10^{-6}$ emu/mole. Since interaction effects tend to increase the susceptibility, and since the model assumes the free electron mass, this prediction agrees reasonably well with the observed susceptibility of $\chi = 72 \times 10^{-6}$ emu/mole.

Refelctivity

In line with their metallic appearance, the reflectivity of $\mathrm{KCu_4S_3}$ crystals in the visible and near ultraviolet was high and almost independent of frequency. There was no sign of a plasma edge over the spectral range studied (roughly 1-4 eV). The simple free electron band picture predicts a plasma edge given by

$$\lambda_0 = 2\pi (\frac{\text{mc}^2}{4\pi} (\frac{N}{V}) e^2)^{1/2}$$

Again assuming the free electron mass, the lack of a plasma edge over the spectral region examined indicates a carrier density greater than about 10^{22} cm⁻³. This is in reasonable agreement with our expectations of 7.1 x 10^{21} cm⁻³, given the formal electronic configurations (d^{10} , d^{10} , d^{10} , d^{9}) of the four Cu ions. Conclusion

 KCu_4S_3 is a structurally unique material with high (metallic) electrical conductivity. As with other layered conductors, chemical modification by intercalation may be possible, and we are currently pursuing such studies. KCu_4S_3 appears to be only one member of a series of mixed-valence alkali copper sulfides, and it is likely that other reported examples - e.g., $RbCu_4S_3$, $K_3Cu_8S_6$, etc. - will exhibit highly anisotropic metallic conductivity. We will report on these materials at a future date.

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References

- a. University of Vermont b. State University of New York at Albany
 c. University of North Carolina, Chapel Hill d. University of Oxford
- 2. Little, W. A. Phys. Rev. 1964, A134, 1416.
- 3. Hullinger, F. Structural Chemistry of layer-type phases, "Physics and Chemistry of Materials with Layered Structure", vol. 5, F. Levy, ed.; D. Reidel Publishing Company: Dordrecht, Holland, 1976.
- 4. Di Salvo, F. J; Bagley, B. G; Voorhoeve, J. M.; Waszczak, J. V.; <u>J. Phys. Chem. Solids</u>, 1973, 34, 1357.
- 5. Rudorff, W., Schwarz, H. G., and Walter, M.; <u>Z. Anorg. Allg. Chem.</u> 1952 269, 141.
- 6. Robin, M. B., Day P.; Adv. Inorg. Chem. Radiochem. 1967, 10, 248.
- 7. 'Molecular Metals', W. E. Hatfield, ed., Plenum Press: New York, 1979.
- 8. Valdes, L. B.; Proc. I.R.E. 1954, 42, 420.
- 9. van der Pauw, L. J.; Philips Res. Rep. 1958, 13, 1.
- 10. Brown, D. B.; Crawford, V. H.; Hall, J. W.; Hatfield, W. E.; <u>J. Phys. Chem.</u> 1977, <u>81</u>, 1303.
- 11. McKim, F. R.; Wolf, W. P.; J. Sci. Instrum. 1957, 34, 64.
- 12. Figgis, B. N.; Lewis, J.; In 'Modern Coordination Chemistry:, Lewis, J. and Wilkins, R. G., Editors, Interscience Publishers, Inc.: New York, 1960, Chapter 6; Page 403.
- König, E., 'Magnetic Properties of Transition Metal Compounds', Springer-Verlag: Berlin; 1966.
- 14. Weller, R. R.; Hatfield, W. E.; submitted for publication.
- 15. The crystallographic programs used in the structure solution and refinement were those compiled in the 1972 version of the X-ray system described by Stewart, J. M.; Fruger, G. J.; Ammon, H. L.; Dickinson, C. and Hall, S.R., Technical Report, TR-192, University of Maryland, 1972.
- 16. "International Table for X-Ray Crystallography," Vol. III, pp. 202, 204.

- 17. Berry, L. G. <u>Amer. Mineralogist</u> 1954, 39, 504.
- 18. Buerger, M. J.; Wuensch, B. J. Science 1963, 141, 276.
- 19. O'Keeffe, M.; Hyde, B.G.J. Solid State Chem. 1975, 13, 172.
- 20. Evans, H. T. Nature Phys. Sci. 1971, 232, 69.
- 21. Janosi, A. Acta Cryst. 1964, 17, 311.
- 22. Morimoto, N.; Kullerud, G. Amer. Mineralogist 1963, 48, 110.
- 23. Binnie, W. P.; Redman, M. J.; Mallio, W. J. <u>Inorg</u>. <u>Chem</u>. <u>1970</u>, <u>9</u>, 1449.
- 24. Gattow, G. Acta Cryst. 1957, 10, 549.
- 25. Flahaut, J.; Domange, L.; Guittard, M.; Ourmitchi, M.; Kam Su Kom, J. Bull. Soc. Chim. Fr. 1961, 2382.
- 26. Hahn, H.; de Lorent, C.; Harder, B. Z. Anorg. Chem. 1956, 283, 138.
- 27. Hahn, H.; Harder, B. Z. Anorg. Chem. 1956, 288, 257.
- 28. Craig, D. C.; Stephenson, N.C. Acta Cryst. 1965, 19, 543.
- 29. Frueh, A. J., Jr. Z. Krist. 1955, 106, 299.
- 30. Hofmann, W. Z. Krist. 1933, 84, 177.
- 31. Wuensch, B. J. Z. Krist. 1964, 119, 437.
- 32. Marumo, F.; Nowacki, W. Z. Krist. 1967, 124, 1.
- 33. Adiwidjaja, von G.; Lohn, J. Acta Cryst. 1970, B26, 1878.
- 34. Hultgren, R. Z. Krist. 1933, 84, 204.
- 35. Azaroff, L.V.; Buerger, M.J. Amer. Mineralogist 1955, 40, 213.
- 36. Morimoto, N. Acta Cryst. 1964, 17, 351.
- 37. Pauling, L.; Brockway, L. O. Z. Krist 1932, 82, 188.
- 38. Brockway, L. O. Z. Krist 1934, 89, 434.
- 39. Savelsberg, G.; Schaefer, H. Z. Naturforsch. 1978, 336, 711.
- 40. Burschka, C.; Bronger, W. Z. <u>Naturforsch.</u> 1977, 326, 11.

- 41. Iglesias, J.E.; Pachali, K.E.; Steinfink, H., Mat. Res. Bull. 1972, 7, 1247.
- 42. Bronger, W.; Burschka, C., Z. Anorg. Allg. Chem. 1976, 425, 109.
- 43. Kassman, A. J., J. Appl. Phys. 1978, 48, 2793.
- 44. Huntley D. J. and Frindt, R. F., 'Optical and Electrical Properties', P. A. Lee (ed.); D. Reidel: Dordrecht, Holland, 1976, p. 385.
- 45. Goodenough, J. B., 'Magnetism and the Chemical Bond'; Interscience: New York, 1963.
- 46. Eliezer, Z., Steinfink, H., Mat. Res. Bull. 1976, 11, 385.
- 47. Kittel, C. "Introduction to Solid State Physics," 5th ed.; Wiley: New York, 1976.

Table I Crystal Data for $\mathrm{KCu_4}^{\mathrm{S}_3}$

$$a = b = 3.899(4)$$
Å

1 = 7

 $V = 140.8(1)^{03}$

 ρ calc. = 4.590g cm⁻³

 $\rho \text{ found = 4.59(2)g cm}^{-3}$

(pycnometrically in xylene at 20°)

Data Collection

Crystal dimensions: $0.152 \times 0.149 \times 0.150 \text{ nm}$

 $\mu(Mo~Ka) = 170.56~cm^{-1}$

311 symmetry-independent reflections for 2<20<50°

113 0.0 0.0 0.0 0.0 0.0 0.0 0.0 17.3(15) 12.2(14) 12.1(10) ^aEstimated standard deviations are given in parenthesis. ^bUij^{x10⁴} 24.6(5) Table II Final Positional and Anisotropic Thermal Parameters^{a,b} 27.9(f) 20.7(6) U₂₂ 25.6(12) 25.6 18.2(11) 18.2 .2944(3) 18.0(8) 18.0 .1603(2) .5000 0000 .5000 0000 0000 0000 2000 0000 0000 .5000 3 25

The vibrational coefficients relate to the expression T=exp[-2* $^2(u_{11}^{*2} + u_{22}^{*2} + u_{33}^{2}]^2$ + $2u_{12}^{*2}$ + $2u_{13}^{*2}$ kla*c* + $2u_{23}$ klb*c*)]

0.0

0.0

0.0

0.0

Table III Internuclear Distances, Polyhedral Edge Lengths, and Bond Angles

ces, Aa,b	3.701(1)	3.351(2)	3.899	3.808(4)	Distances, A	3.878(2)		
(i) Interatomic Distances, Aa,b	Cu-K(4)	K-S2(8)	K-K(4)	\$2-\$2	(ii) Polyhedral Edge Distances, A	51-52		
	2.4506(9)	2,312(2)	2.7570	2.970(2)		3.899	3.899	
	Cu-S1(2)	Cu-S2(2)	Cu-Cu(4)	Cu-Cu(1)		19-19	52-52	

(iii) Bond Angles, deg.

	73.22(7)	114.99(14)					
	Cu-S ₂ -Cu						
105.41(6)	109.00(4)	114.99(11)	68.46(2)	74.59(4)	105.41(4)	111.54(2)	
S1-Cu-S1	S1-Cu-S2	S2-Cu-S2	Cu-S1-Cu				

The number of equivalent bonds of a given type is indicated in parenthesis. Standard deviations are given in parentheses. e a

	References	10	18,19	20	21	22	23	24	25
c	Bond Lengths, A	Cul-5, 2.19 Cu2-5, 2.32	Cul-S, 2.28 Cu2-S, 2.59(3x), 2.15(1x) Cu3-S, 2.06 Cu1-Cu 2, 2.59	Cu-S, 2.33 (mean) 2.88	Cu-S, 2.31 Cu-Cu, 2.64(x2) 2.97(x2)	•	Cu-S, 2.31(3)	Cu-S, 2.31(x1) 2.37(x2) Cu-Cu,2.83(x4) 2.94(x1)	Cu-S 2.34 Cu-S 2.59
	Description of Overall Structure	3-D network, $2/3$ of Satoms present as 5_2 .	3-D network, hexagonal closepacked S framework	3-D network, hexagonal closepacked S framework	3-D network cubic closest packing of S atoms	3-D network	Infinite chain, 2 tetrahedral edges shared	3-D, crosslinked columns	Spinel structure
Copper-Sulfide Lattices	Copper Coordination	Cu 1, trigonal planar Cu 2, tetrahedral	hexagonal Cul, trigonal planar from Cu 2, tetrahedral Cu 3, linear	Trigonal planar	Trigonal planar	Tetrahedral	Tetrahedral	Trigonal	Tetrahedral
Table IV Co	Compound	Smo	Cu ₂ S, hexagon from	Cu ₂ S, mono- clinic form	Cu 1.96 _s	Cu 1.8 _s	NH4CuMoS4	NH4Cu7S4	Cu8 ₅ 5 ₈ 8=A1 8=In

Lattices
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Copper-Sulfide
3
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ap

Table IV (Con't)	Table IV (Con't) Copper-Sulfide Lattices			
Compound	Copper Coordination	Description of Overall Structure	Bond Lengths, A	References
CuB ₂ S ₄ B=Cr Ti	Tetrahedral	Spinel structure	Cu-S, 2.18 Cu-S, 2.26 Cu-S, 2.28	26 27 26
CuAsS	Tetrahedral	3-D network of vertex- sharing tetrahedra	Cu-S, 2.30(1) 2.24(1) 2.34(1) Cu-As,2.416(6)	28
CuAgS	Trigonal planar	Alternate layers	Cu-5, 2.29(x2) 2.26(x1)	29
CuSbS ₂	Tetrahedral	3-D network of vertex- shaving tetrahedra	Cu-S, 2.25(x1) 2.29(x1) 2.33(x2)	30
Cu ₁₂ Sb ₁₄ S ₁₃	Cu 1, trigonal planar Cu 2, tetrahedral	Sphalerite superstructure, vertex sharing network	Cul-S, 2.234(x1) 2.272(x2)	31
Cu ₃ AsS ₄ ,I Cu ₃ VS ₄	Tetrahedral Tetrahedral Tetrahedral	Zinc-blende Wurtzite 3-D, edge-sharing network	Cu-S, 2.302-2.337(1) Cu1-S, 2.312-2.323 Cu2-S, 2.302-2.381 Cu-S, 2.29(1)	(1) 32 3 33 1 34
CuFe ₂ S ₃	Tetrahedral	Wurtzite layers with edge-sharing Fe tetrahedra	Cu-S, 2.31(av)	35
Cu ₅ FeS ₄	Tetrahedral	3-D network	Cu-S, 2.20-2.94	36
CufeS ₂	Tetrahedral	3-D vertex-sharing network, Zinc-blende superstructure	Cu-S, 2.26	37
Cu ₂ FeSnS ₄	Tetrahedral	Derived from CuFeS ₂ by substitution of 1/2 Fe by Sn atoms	Cu-S, 2.31	38

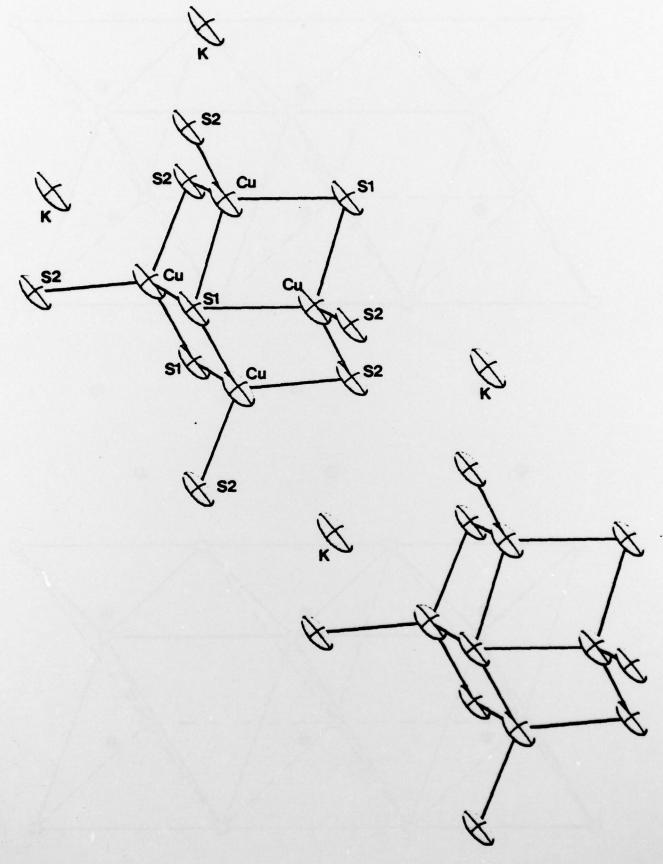
Table IV (con't) Copper-Sulfide Lattices

References	39	40	41	5 this work
Bond Lengths, A°	Cu-S, 2.13(2) 2.16(2) Cu-Cu, 2.66(2) (x2)	Cul-S, 2.53 (mean) Cu2-S, 2.58 (mean)	Cu-S, 2.24-2.70 Cu-Cu, 2.573-2.965	Cu-S, 2.450(1) (x2) 2.312(2) (x2) Cu-Cu, 2.757(x4) 2.967(x1)
Description of Overall Structure	Zig-zag Cu-S chains	Pleated layers	Interwoven copper chains	Double layer, 5 edges/ 4 vertices shared
Copper Coordination	Square planar	Tetrahedral	Trigonal Planar, Tetrahedral	Tetrahedral
Compound	KOuS	KOu ₃ S ₂	BaOu ₄ S ₃	KOu ₄ S ₃

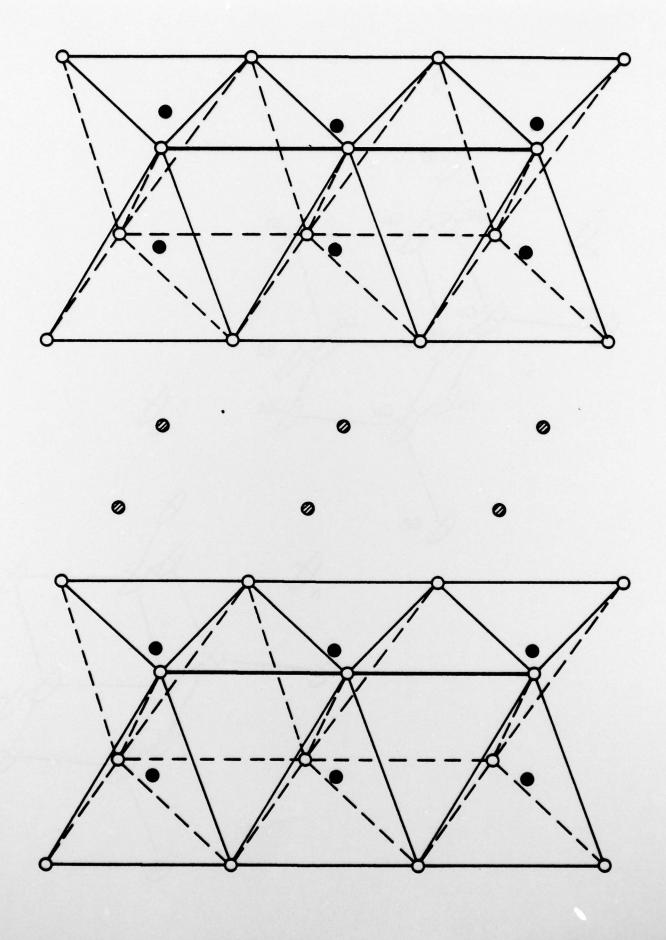
Figure Captions

- Fig. 1 The atom-labelling scheme and the 50% thermal ellipsoids for KCu_4S_3 , illustrating the position of the K^+ layers relative to the Cu-S double layers.
- Fig. 2 Schematic representation of a portion of adjacent double-layers showing the octahedral holes. The shaded circles represent Cu positions, the open circles S, and the crossed circles K.
- Fig. 3 A view down the c-axis of the edge and vertex-sharing tetrahedra that comprise a Cu-S layer.
- Fig. 4 Temperature dependence of the compaction conductivity of KCu_4S_3 .

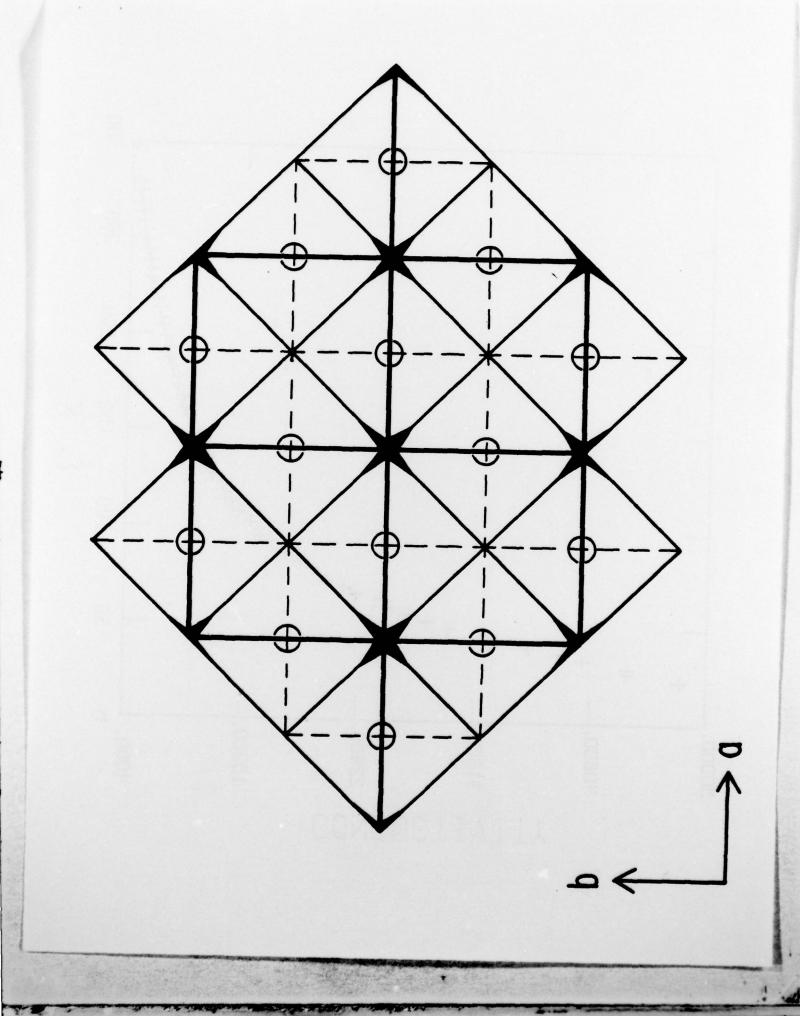
 Units of conductivity are Ω^{-1} cm⁻¹.
- Fig. 5 Magnetic data for KCu₄S₃.

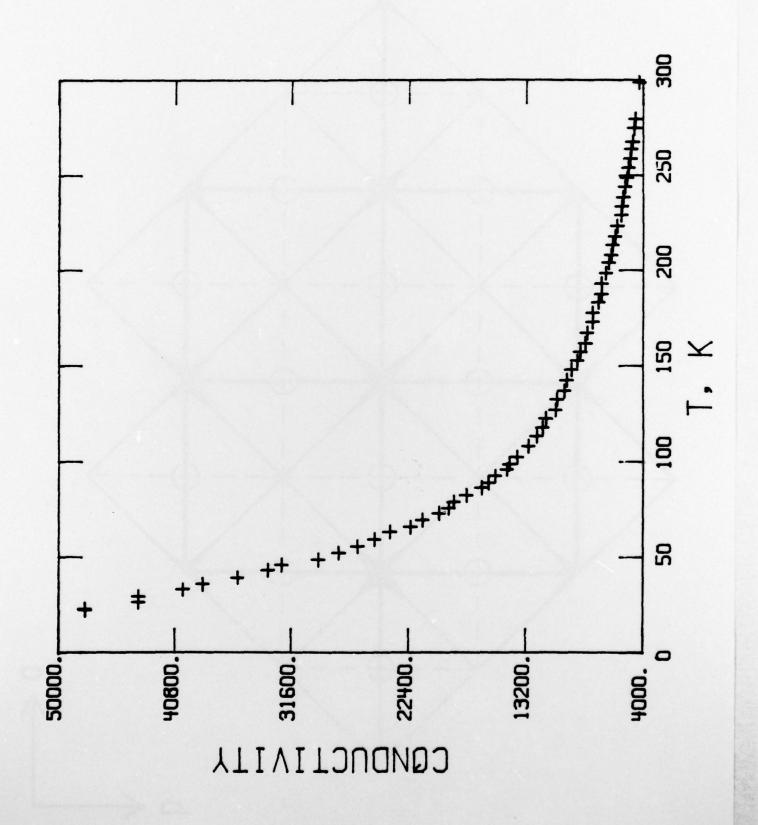


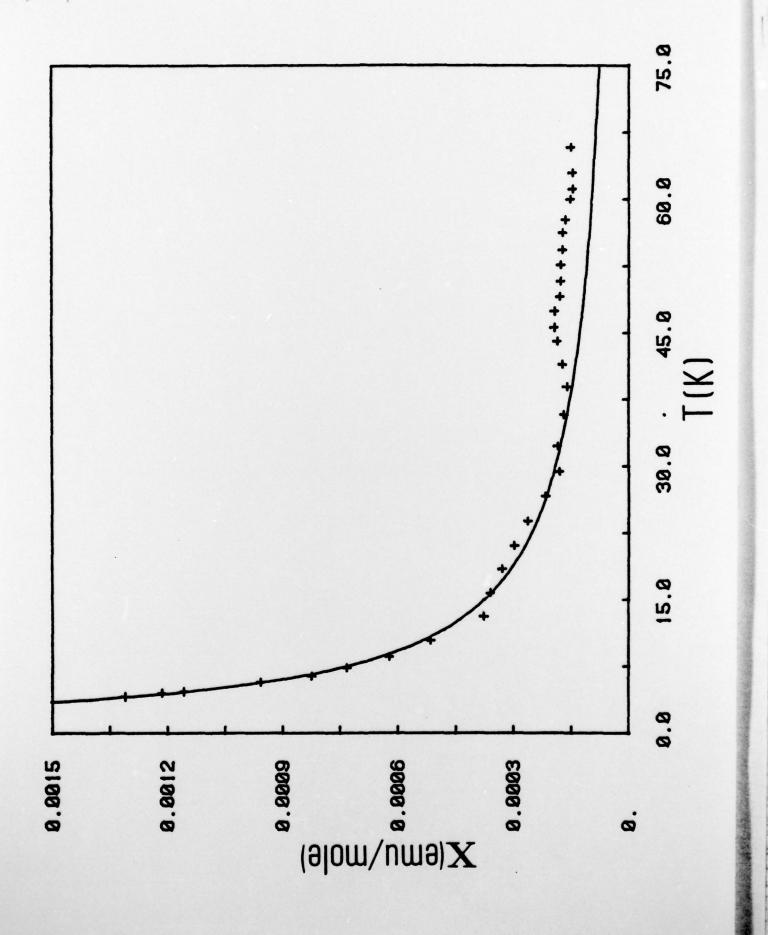
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